National Semiconductor

# LM108/LM208/LM308 Operational Amplifiers

#### **General Description**

The LM108 series are precision operational amplifiers having specifications a factor of ten better than FET amplifiers over a  $-55^\circ\text{C}$  to  $+125^\circ\text{C}$  temperature range.

The devices operate with supply voltages from  $\pm 2V$  to  $\pm 20V$  and have sufficient supply rejection to use unregulated supplies. Although the circuit is interchangeable with and uses the same compensation as the LM101A, an alternate compensation scheme can be used to make it particularly insensitive to power supply noise and to make supply by pass capacitors unnecessary.

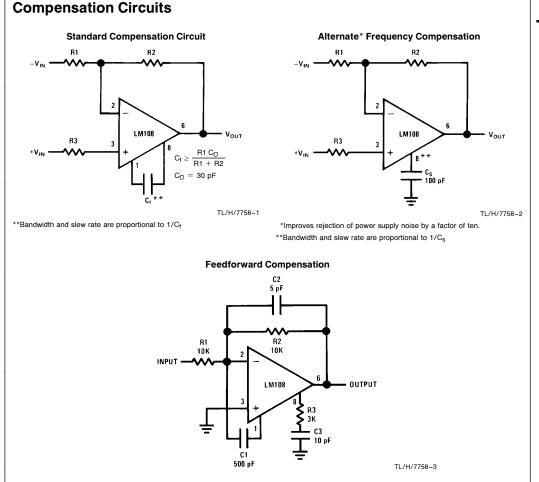
The low current error of the LM108 series makes possible many designs that are not practical with conventional amplifiers. In fact, it operates from 10 M $\Omega$  source resistances,

introducing less error than devices like the 709 with 10 k $\Omega$  sources. Integrators with drifts less than 500  $\mu$ V/sec and analog time delays in excess of one hour can be made using capacitors no larger than 1  $\mu$ F.

The LM108 is guaranteed from  $-55^\circ C$  to  $+125^\circ C$ , the LM208 from  $-25^\circ C$  to  $+85^\circ C$ , and the LM308 from 0°C to  $+70^\circ C.$ 

#### **Features**

- Maximum input bias current of 3.0 nA over temperature
- Offset current less than 400 pA over temperature
- Supply current of only 300 µA, even in saturation
- Guaranteed drift characteristics



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### **Absolute Maximum Ratings**

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications. (Note 5)

	LM108/LM208	LM308	
Supply Voltage	$\pm$ 20V	±18V	
Power Dissipation (Note 1)	500 mW	500 mW	
Differential Input Current (Note 2)	$\pm$ 10 mA	±10 mA	
Input Voltage (Note 3)	$\pm$ 15V	$\pm 15V$	
Output Short-Circuit Duration	Continuous	Continuous	
Operating Temperature Range (LM108)	-55°C to +125°C	0°C to +70°C	
(LM208)	-25°C to + 85°C		
Storage Temperature Range	-65°C to +150°C	-65°C to +150°C	
Lead Temperature (Soldering, 10 sec)			
DIP	260°C	260°C	
H Package Lead Temp			
(Soldering 10 seconds)	300°C	300°C	
Soldering Information			
Dual-In-Line Package			
Soldering (10 seconds)	260°C		
Small Outline Package			
Vapor Phase (60 seconds)	215°C		
Infrared (15 seconds)	220°C		
See AN-450 "Surface Mounting Methods and Th Reliability" for other methods of soldering surfac			
ESD Tolerance (Note 6)	2000V		

## **Electrical Characteristics** (Note 4)

Parameter	Condition	LM108/LM208		LM308			Units	
Farameter	Min		Тур	Тур Мах	Min	Тур	Max	Units
Input Offset Voltage	T <sub>A</sub> = 25°C		0.7	2.0		2.0	7.5	mV
Input Offset Current	T <sub>A</sub> = 25°C		0.05	0.2		0.2	1	nA
Input Bias Current	T <sub>A</sub> = 25°C		0.8	2.0		1.5	7	nA
Input Resistance	$T_A = 25^{\circ}C$	30	70		10	40		MΩ
Supply Current	$T_A = 25^{\circ}C$		0.3	0.6		0.3	0.8	mA
Large Signal Voltage Gain	$\begin{array}{l} T_A=25^{\circ}C, V_S=\pm 15V\\ V_{OUT}=\pm 10V, R_L\geq 10\ k\Omega \end{array}$	50	300		25	300		V/mV
Input Offset Voltage				3.0			10	mV
Average Temperature Coefficient of Input Offset Voltage			3.0	15		6.0	30	μV/°C
Input Offset Current				0.4			1.5	nA
Average Temperature Coefficient of Input Offset Current			0.5	2.5		2.0	10	pA/°C
Input Bias Current				3.0			10	nA
Supply Current	T <sub>A</sub> = +125°C		0.15	0.4				mA
Large Signal Voltage Gain	$\label{eq:VS} \begin{array}{l} V_S=\pm 15V, V_{OUT}=\pm 10V\\ R_L\geq 10\ k\Omega \end{array}$	25			15			V/mV
Output Voltage Swing	$V_{S} = \pm 15V, R_{I} = 10 k\Omega$	±13	±14		±13	±14		V

Parameter Condit	Condition	LM108/LM208			LM308			Units
i arameter		Min	Тур	Max	Min	Тур	Мах	51113
Input Voltage Range	$V_{S} = \pm 15V$	±13.5			±14			V
Common Mode Rejection Ratio		85	100		80	100		dB
Supply Voltage Rejection Ratio		80	96		80	96		dB

Note 1: The maximum junction temperature of the LM108 is 150°C, for the LM208, 100°C and for the LM308, 85°C. For operating at elevated temperatures, devices in the H08 package must be derated based on a thermal resistance of 160°C/W, junction to ambient, or 20°C/W, junction to case. The thermal resistance of the dual-in-line package is 100°C/W, junction to ambient.

Note 2: The inputs are shunted with back-to-back diodes for overvoltage protection. Therefore, excessive current will flow if a differential input voltage in excess of 1V is applied between the inputs unless some limiting resistance is used.

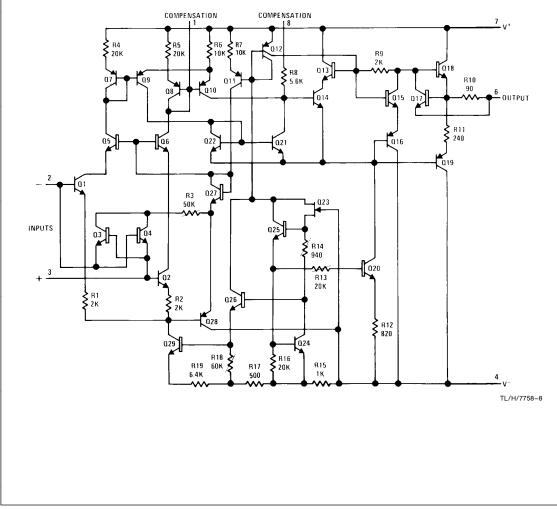
Note 3: For supply voltages less than  $\pm$ 15V, the absolute maximum input voltage is equal to the supply voltage.

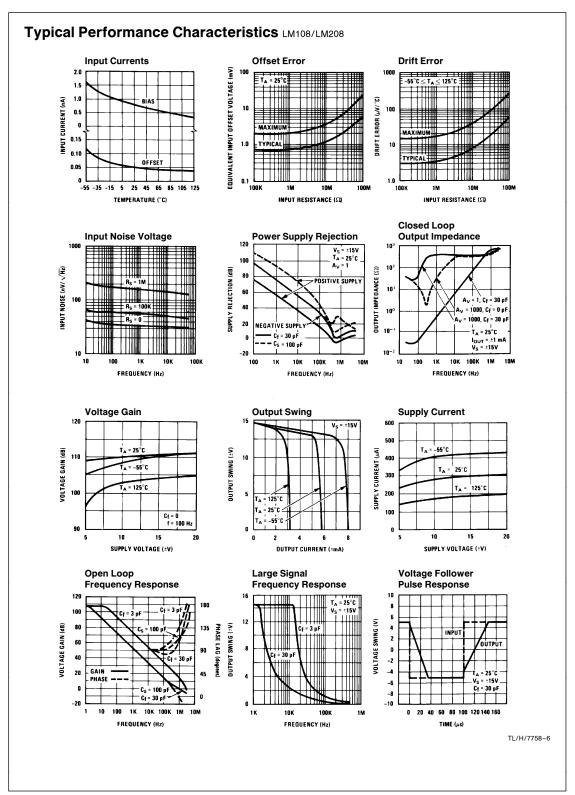
Note 4: These specifications apply for  $\pm 5V \le V_S \le \pm 20V$  and  $-55^{\circ}C \le T_A \le + 125^{\circ}C$ , unless otherwise specifications are limited to  $-25^{\circ}C \le T_A \le 85^{\circ}C$ , and for the LM308 they are limited to  $0^{\circ}C \le T_A \le 70^{\circ}C$ .

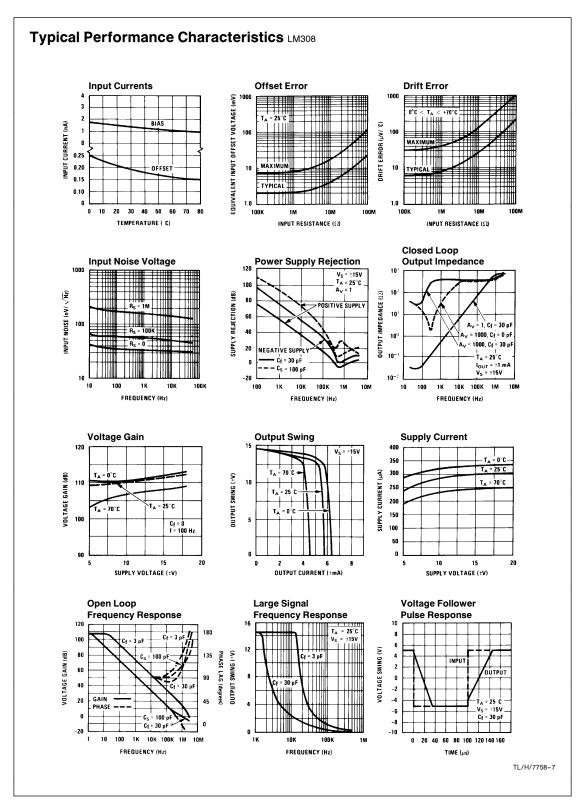
Note 5: Refer to RETS108X for LM108 military specifications and RETs 108AX for LM108A military specifications.

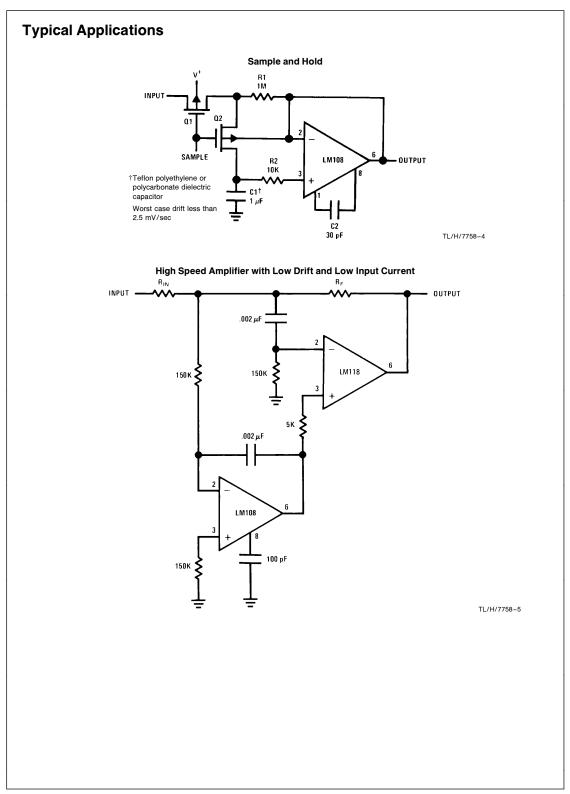
Note 6: Human body model, 1.5 k $\Omega$  in series with 100 pF.

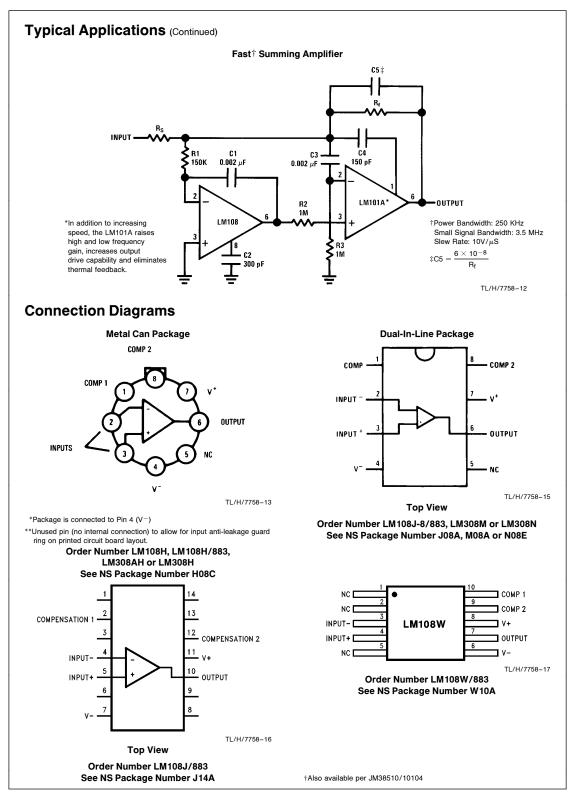
### Schematic Diagram

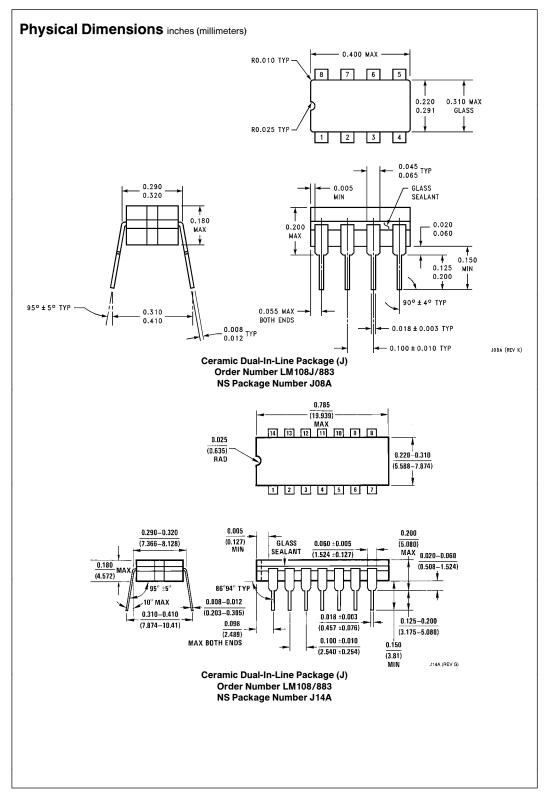


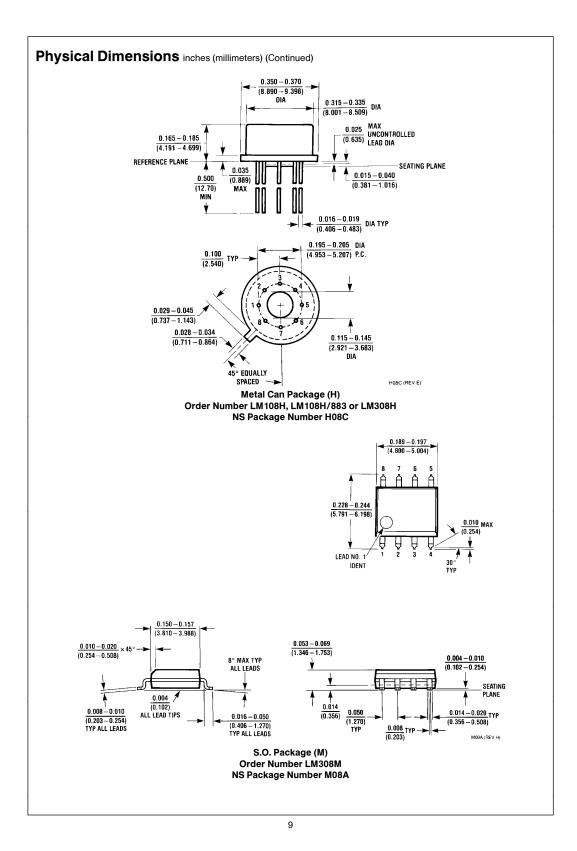


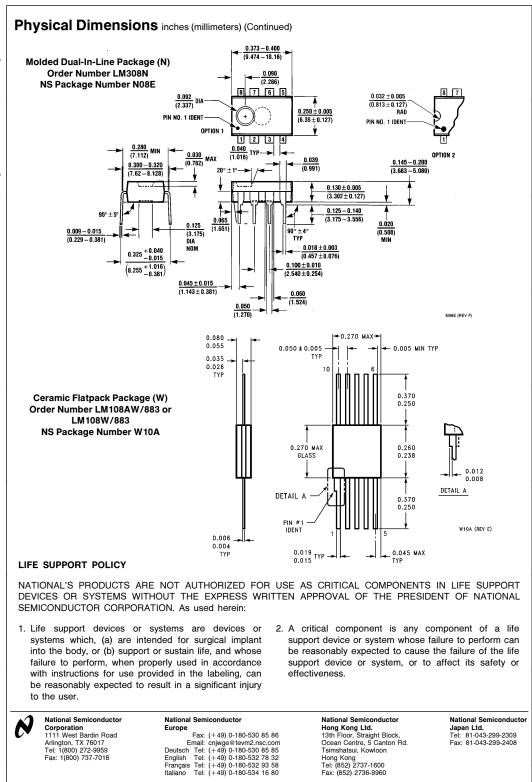












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